

**SWITCHING  
 N-CHANNEL POWER MOS FET**

**DESCRIPTION**

The 2SK3113B is N-channel MOS FET device that features a low gate charge and excellent switching characteristics, and designed for high voltage applications such as switching power supply, AC adapter.

**FEATURES**

- Low on-state resistance  
 $R_{DS(on)} = 4.4 \Omega \text{ MAX. (} V_{GS} = 10 \text{ V, } I_D = 1.0 \text{ A)}$
- Low gate charge  
 $Q_G = 7.9 \text{ nC TYP. (} V_{DD} = 450 \text{ V, } V_{GS} = 10 \text{ V, } I_D = 2.0 \text{ A)}$
- Gate voltage rating :  $\pm 30 \text{ V}$
- Avalanche capability ratings

<R> **ORDERING INFORMATION**

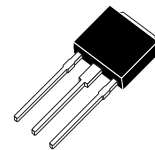
PART NUMBER	LEAD PLATING	PACKING	PACKAGE
2SK3113B-S15-AY <sup>Note</sup>	Pure Sn (Tin)	Tube 70 p/tube	TO-251 (MP-3-a) typ. 0.39 g
2SK3113B(1)-S27-AY <sup>Note</sup>		Tube 75 p/tube	TO-251 (MP-3-b) typ. 0.34 g
2SK3113B-ZK-E1-AY <sup>Note</sup>		Tape 2500 p/reel	TO-252 (MP-3ZK) typ. 0.27 g
2SK3113B-ZK-E2-AY <sup>Note</sup>			

**Note** Pb-free (This product does not contain Pb in external electrode.)

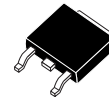
**ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C)**

Drain to Source Voltage (V <sub>GS</sub> = 0 V)	V <sub>DSS</sub>	600	V
Gate to Source Voltage (V <sub>DS</sub> = 0 V)	V <sub>GSS</sub>	$\pm 30$	V
Drain Current (DC) (T <sub>C</sub> = 25°C)	I <sub>D(DC)</sub>	$\pm 2.0$	A
Drain Current (pulse) <sup>Note1</sup>	I <sub>D(pulse)</sub>	$\pm 8.0$	A
Total Power Dissipation (T <sub>C</sub> = 25°C)	P <sub>T1</sub>	20	W
Total Power Dissipation (T <sub>A</sub> = 25°C) <sup>Note2</sup>	P <sub>T2</sub>	1.0	W
Channel Temperature	T <sub>ch</sub>	150	°C
Storage Temperature	T <sub>stg</sub>	-55 to +150	°C
Single Avalanche Current <sup>Note3</sup>	I <sub>AS</sub>	2.0	A
Single Avalanche Energy <sup>Note3</sup>	E <sub>AS</sub>	2.7	mJ

(TO-251)



(TO-252)



**Notes** 1.  $PW \leq 10 \mu s$ , Duty Cycle  $\leq 1\%$

2. Mounted on glass epoxy board of 40 mm × 40 mm × 1.6 mm

3. Starting T<sub>ch</sub> = 25°C, V<sub>DD</sub> = 150 V, R<sub>G</sub> = 25 Ω, V<sub>GS</sub> = 20 → 0 V

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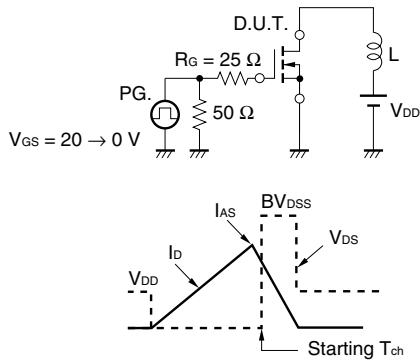
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**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)**

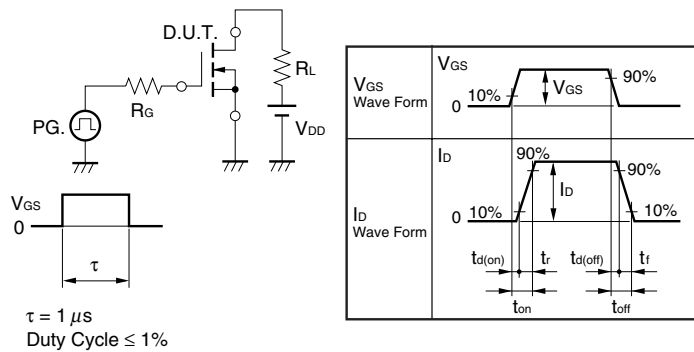
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I <sub>bss</sub>	V <sub>DS</sub> = 600 V, V <sub>GS</sub> = 0 V			100	μA
Gate Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = ±30 V, V <sub>DS</sub> = 0 V			±10	μA
Gate Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	2.5		3.5	V
Forward Transfer Admittance <sup>Note</sup>	y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1.0 A	0.5	0.9		S
Drain to Source On-state Resistance <sup>Note</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 1.0 A		3.2	4.4	Ω
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 10 V		290		pF
Output Capacitance	C <sub>oss</sub>	V <sub>GS</sub> = 0 V		75		pF
Reverse Transfer Capacitance	C <sub>rss</sub>	f = 1 MHz		7		pF
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> = 150 V, I <sub>D</sub> = 1.0 A		10.5		ns
Rise Time	t <sub>r</sub>	V <sub>GS</sub> = 10 V		4.8		ns
Turn-off Delay Time	t <sub>d(off)</sub>	R <sub>G</sub> = 10 Ω		15.8		ns
Fall Time	t <sub>f</sub>	R <sub>L</sub> = 10 Ω		10.5		ns
Total Gate Charge	Q <sub>G</sub>	V <sub>DD</sub> = 450 V		7.9		nC
Gate to Source Charge	Q <sub>GS</sub>	V <sub>GS</sub> = 10 V		2.7		nC
Gate to Drain Charge	Q <sub>GD</sub>	I <sub>D</sub> = 2.0 A		3.2		nC
Body Diode Forward Voltage <sup>Note</sup>	V <sub>F(S-D)</sub>	I <sub>F</sub> = 2.0 A, V <sub>GS</sub> = 0 V		0.8		V
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 2.0 A, V <sub>GS</sub> = 0 V		190		ns
Reverse Recovery Charge	Q <sub>rr</sub>	di/dt = 50 A/μs		500		nC

**Note** Pulsed

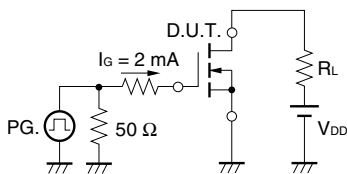
**TEST CIRCUIT 1 AVALANCHE CAPABILITY**



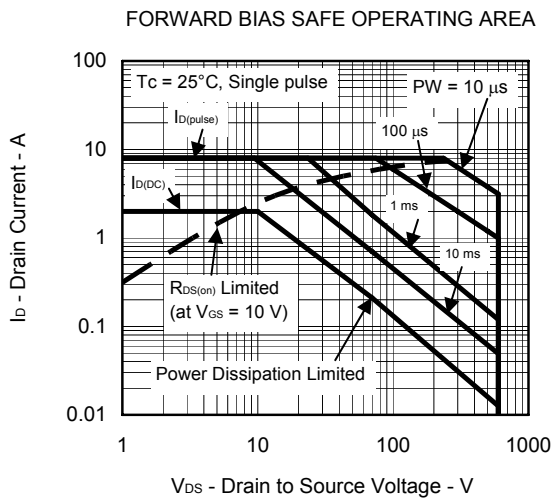
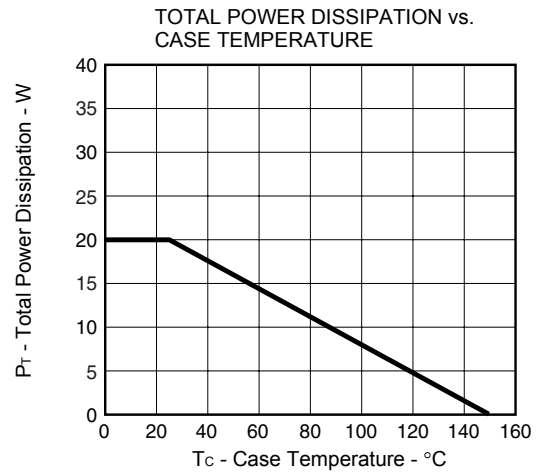
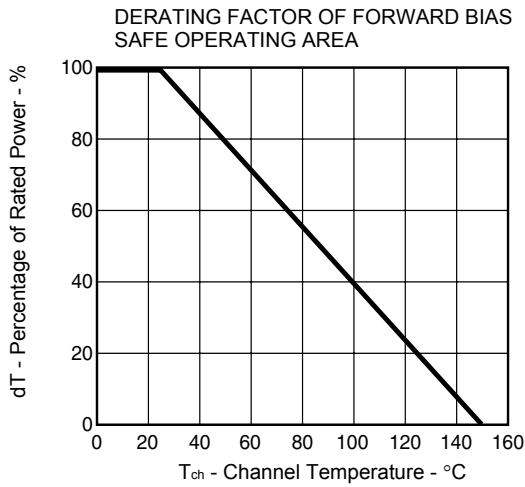
**TEST CIRCUIT 2 SWITCHING TIME**



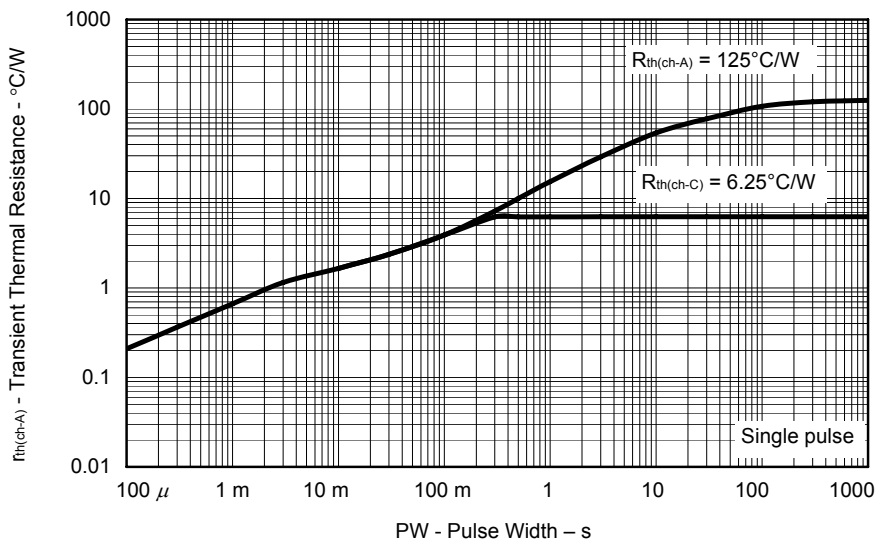
**TEST CIRCUIT 3 GATE CHARGE**



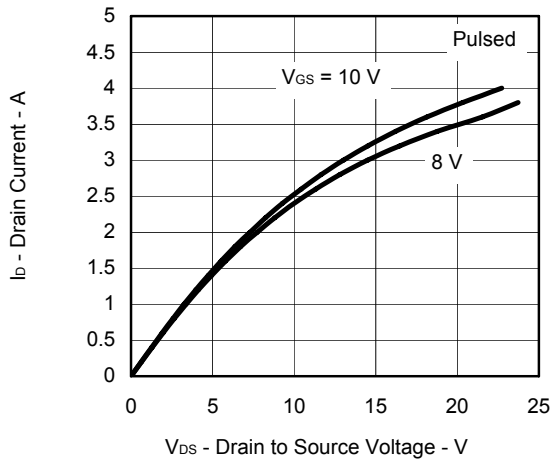
TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)



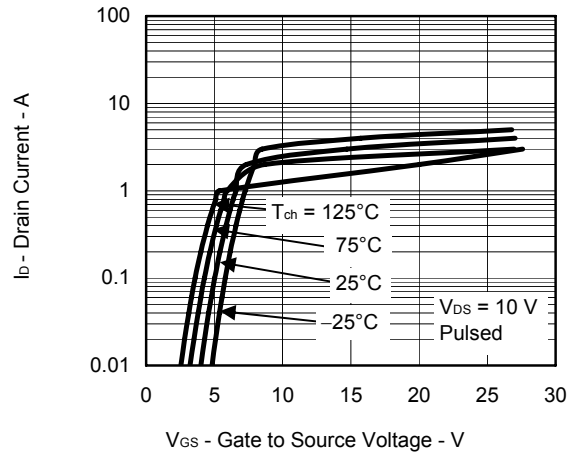
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



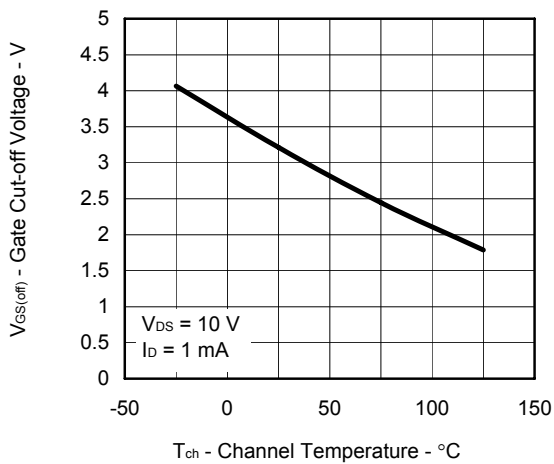
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



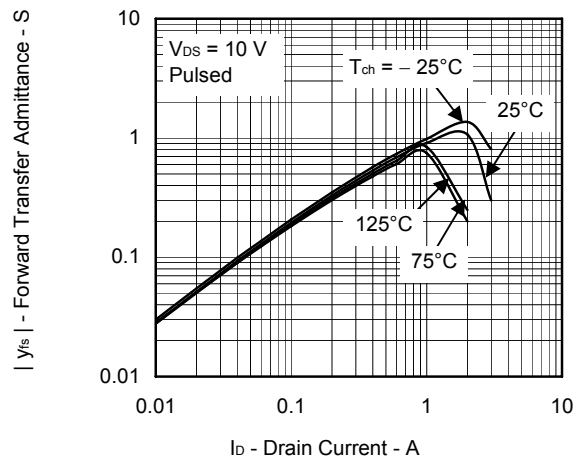
FORWARD TRANSFER CHARACTERISTICS



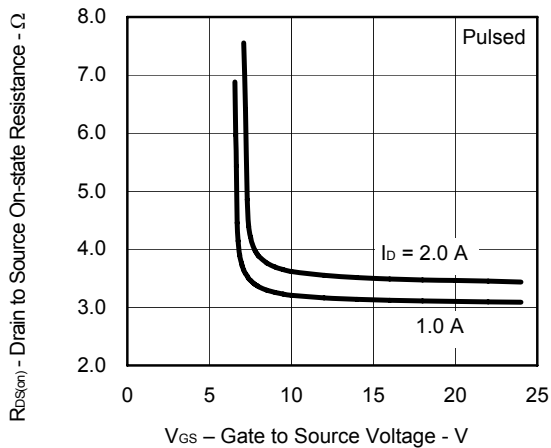
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



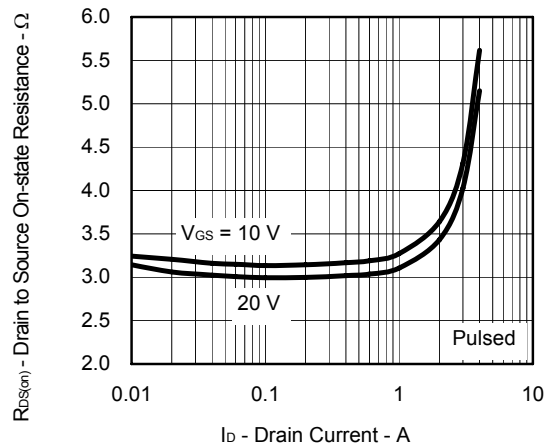
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



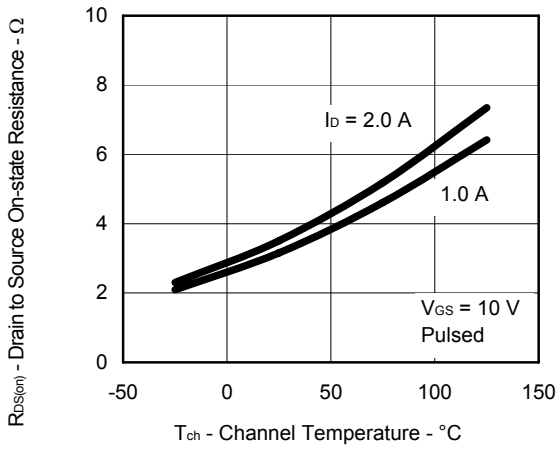
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



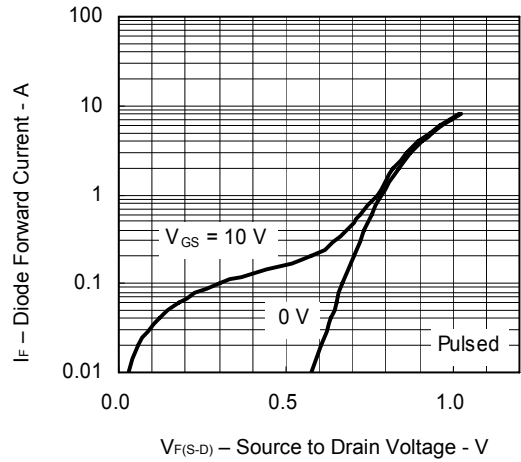
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



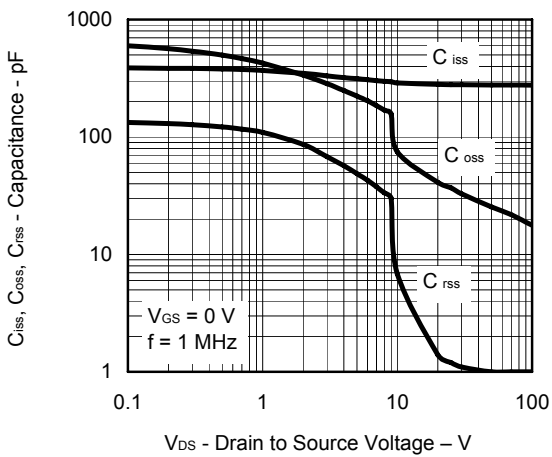
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



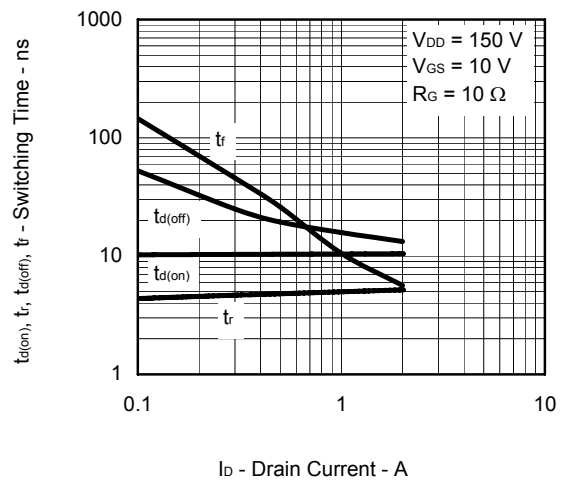
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



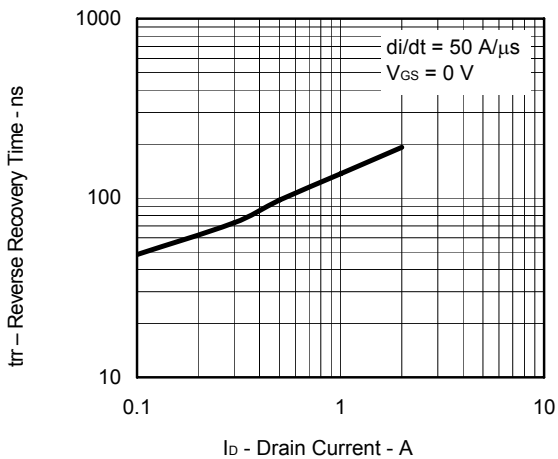
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



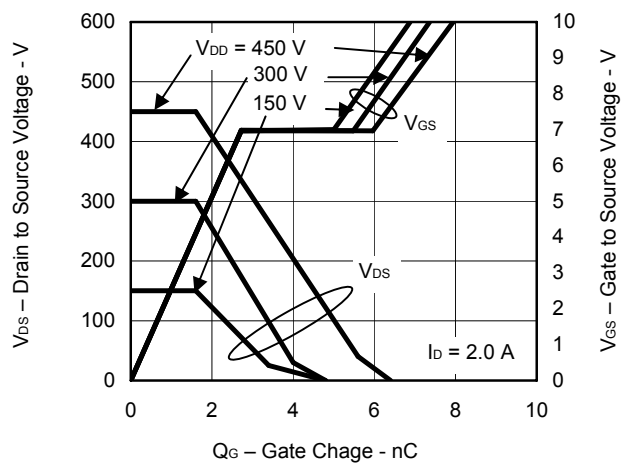
SWITCHING CHARACTERISTICS

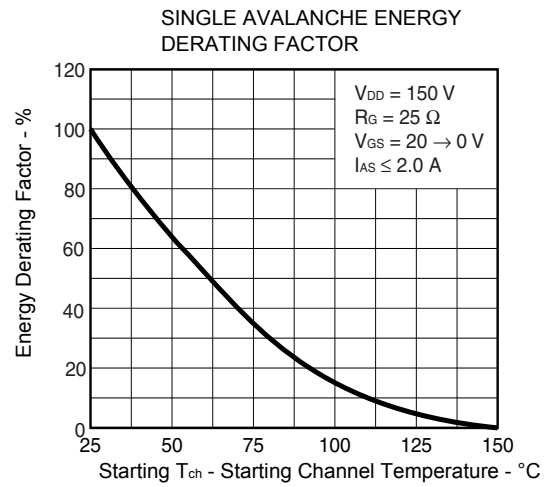
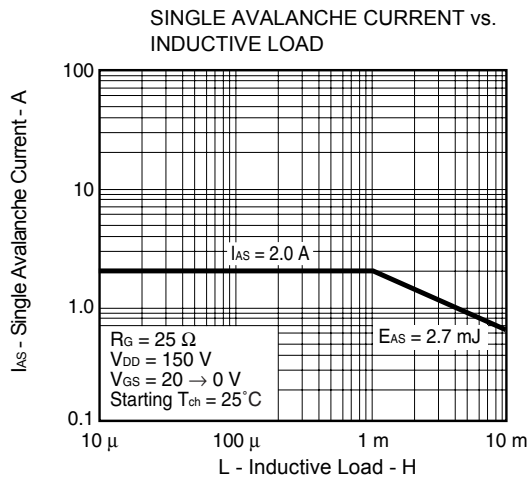


REVERSE RECOVERY TIME vs. DRAIN CURRENT



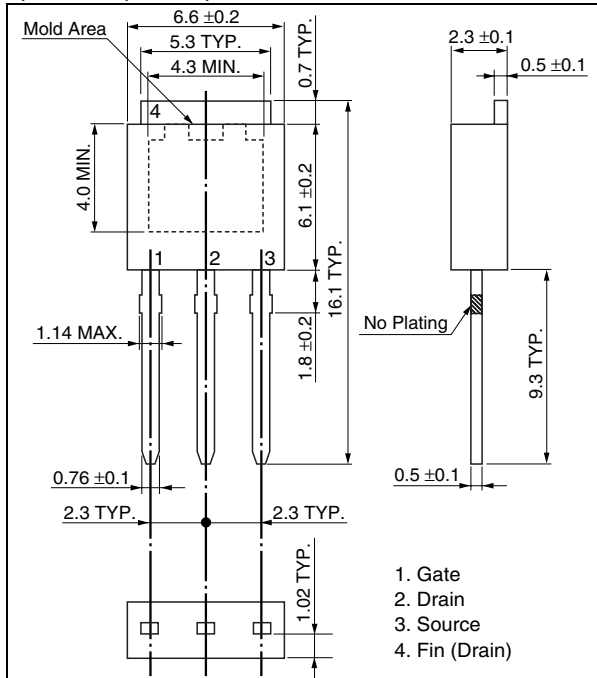
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



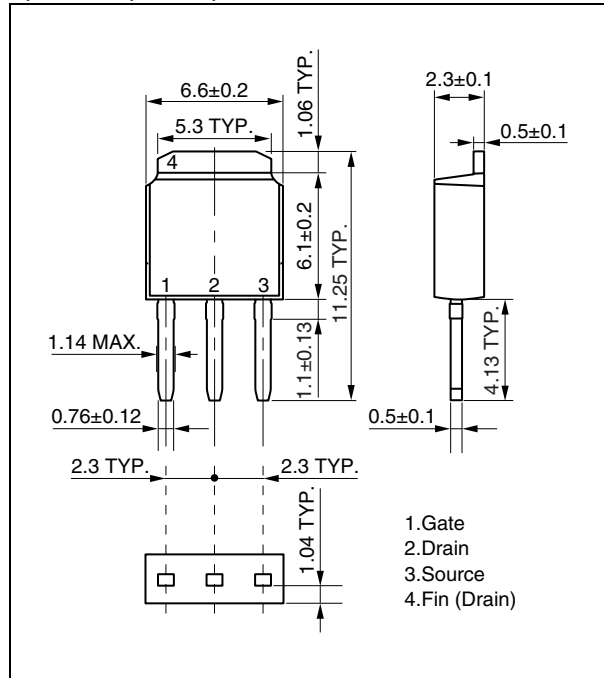


<R> PACKAGE DRAWINGS (Unit: mm)

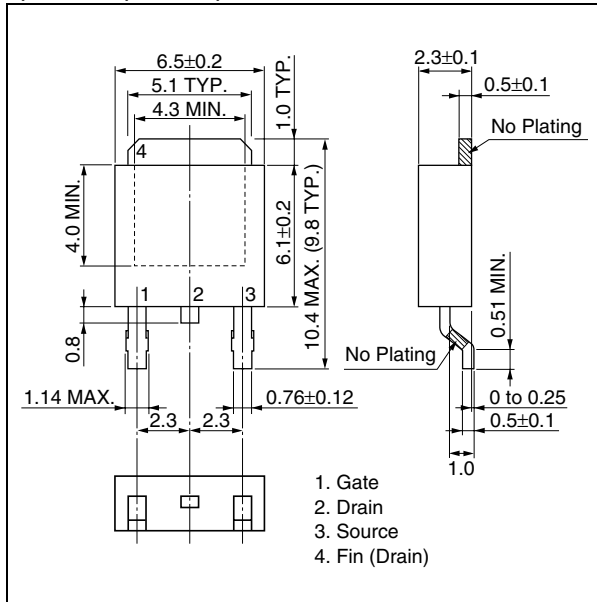
1) TO-251 (MP-3-a)



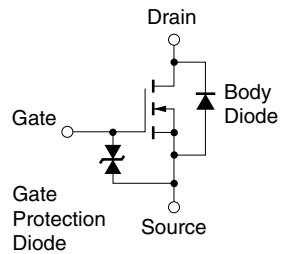
2) TO-251 (MP-3-b)



3) TO-252 (MP-3ZK)



EQUIVALENT CIRCUIT



**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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